

MGA-30789

2 - 6GHz

High Linearity Gain Block



Data Sheet

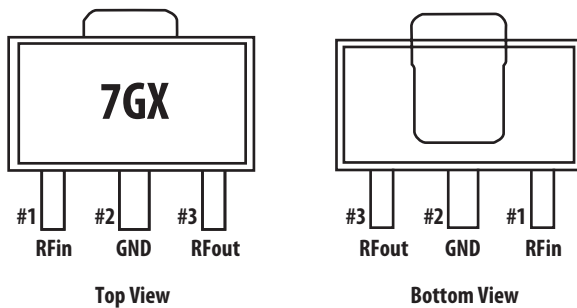
Description

Avago Technologies' MGA-30789 is a broadband, high linearity gain block MMIC amplifier achieved through the use of Avago Technologies' proprietary 0.25um GaAs Enhancement-mode pHEMT process.

The device required simple dc biasing components to achieve wide bandwidth performance. The temperature compensated internal bias circuit provides stable current over temperature and process threshold voltage variation.

The MGA-30789 is housed inside a low cost RoHS compliant SOT89 industry standard SMT package (4.5 x 4.1 x 1.5 mm).

Component Image



Notes:

Package marking provides orientation and identification

"7G" = Device Code

"X" = Month of Manufacture



Attention: Observe precautions for handling electrostatic sensitive devices.

ESD Machine Model = 110 V

ESD Human Body Model = 2000 V

Refer to Avago Application Note A004R:

Electrostatic Discharge, Damage and Control.

Features

- High linearity
- Built in temperature compensated internal bias circuitry
- No RF matching components required
- GaAs E-pHEMT Technology^[1]
- Standard SOT89 package
- Single, Fixed 5V supply
- Excellent uniformity in product specifications
- MSL-1 and Lead-free halogen free
- High MTTF for base station application

Specifications

3.5GHz; 5V, 100mA (typical)

- 11.7 dB Gain
- 41.8 dBm Output IP3
- 3.3 dB Noise Figure
- 25 dBm Output Power at 1dB gain compression

5GHz; 5V, 100mA (typical)

- 8.8 dB Gain
- 40 dBm Output IP3
- 2.7 dB Noise Figure
- 25.7 dBm Output Power at 1dB gain compression

Applications

- RF driver amplifier
- General purpose gain block

Note:

1. Enhancement mode technology employs positive gate voltage, thereby eliminating the need of negative gate voltage associated with conventional depletion mode devices.

Absolute Maximum Rating^[1] T_A=25°C

Symbol	Parameter	Units	Absolute Max.
V _{dd,max}	Device Voltage, RF output to ground	V	5.5
P _{in,max}	CW RF Input Power	dBm	24
P _{diss}	Total Power Dissipation ^[3]	W	0.75
T _{j,MAX}	Junction Temperature	°C	150
T _{STG}	Storage Temperature	°C	-65 to 150

Thermal Resistance

Thermal Resistance^[3] $\theta_{JC} = 52^{\circ}\text{C}/\text{W}$
(V_{dd} = 5, I_{ds} = 88 mA, T_c = 85°C)

Notes:

1. Operation of this device in excess of any of these limits may cause permanent damage.
2. Thermal resistance measured using Infrared measurement technique.
3. This is limited by maximum V_{dd} and I_{ds}. Derate 19.2 mW/°C for T_c > 111°C.

Product Consistency Distribution Charts^[1, 2]

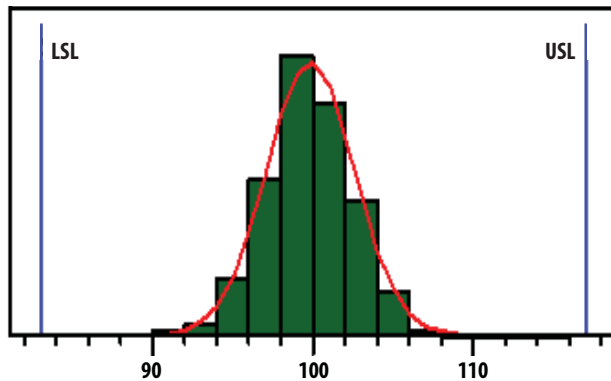


Figure 1. I_{ds}, LSL=83mA, nominal=100mA, USL=117mA

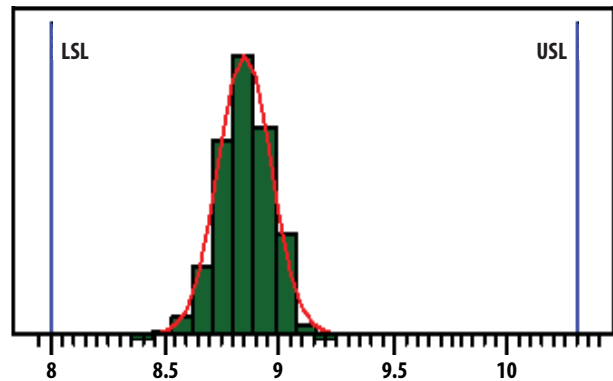


Figure 2. Gain, LSL=8dB, nominal=8.8dB, USL=10.3dB

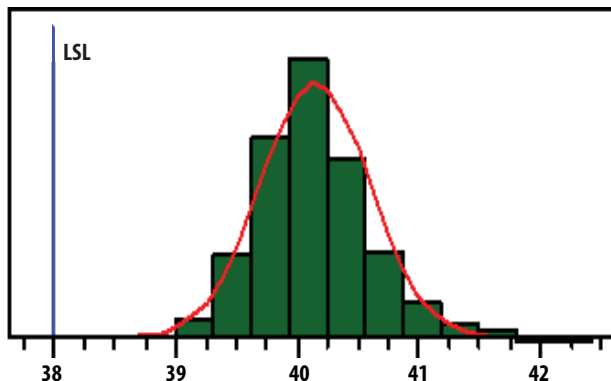


Figure 3. OIP3, LSL=38dBm, nominal=41dBm

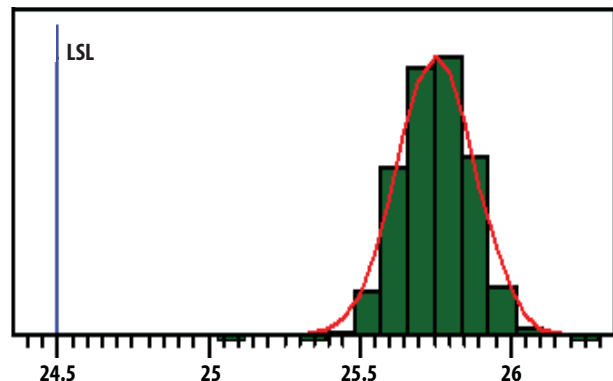


Figure 4. P1dB, LSL=24.5dBm, nominal=25.7dBm

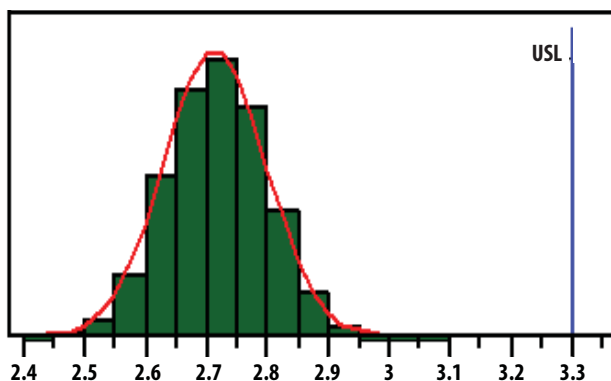


Figure 5. NF, nominal=2.7dB, USL=3.3dB

Notes:

1. Distribution data sample size is 2000 samples taken from 3 different wafer lots. Future wafers allocated to this product may have nominal values anywhere between the upper and lower limits.
2. Measurements were made on a characterization test board, which represents a trade-off between optimal OIP3, gain and P1dB. Circuit trace losses have not been de-embedded from measurements above.

Electrical Specifications [1]

T_A = 25°C, V_{dd} = 5V

Symbol	Parameter and Test Condition	Frequency	Units	Min.	Typ.	Max.
I _{ds}	Quiescent current	N/A	mA	83	100	117
Gain	Gain	3.5 GHz 5 GHz	dB	8	11.8 8.8	10.3
OIP3 [2]	Output Third Order Intercept Point	3.5 GHz 5 GHz	dBm	38	41.8 40	–
NF	Noise Figure	3.5 GHz 5 GHz	dB	–	3.3 2.7	3.3
S11	Input Return Loss, 50Ω source	3.5 GHz 5 GHz	dB		-12 -8.5	
S22	Output Return Loss, 50Ω load	3.5 GHz 5 GHz	dB		-10.5 -9.5	
S12	Reverse Isolation	3.5 GHz 5 GHz	dB		-25 -22	
OP1dB	Output Power at 1dB Gain Compression	3.5 GHz 5 GHz	dBm	24.5	24.5 25.7	–

Notes:

1. Measurements obtained using demo board described in Figure 30 and 31. 3.5GHz data was taken with 3GHz - 4GHz Application Test Circuit and 5GHz data with 4GHz - 6GHz Application Test Circuit respectively.
2. OIP3 test condition: F_{RF1} - F_{RF2} = 10MHz with input power of -10dBm per tone measured at worse side band
3. Use proper bias, heat sink and de-rating to ensure maximum channel temperature is not exceeded. See absolute maximum ratings and application note (if applicable) for more details.

Typical Performance (2GHz - 3GHz)

$T_A = 25^\circ\text{C}$, $V_{dd} = 5\text{V}$, Input Signal = CW unless stated otherwise. Application Test Circuit is shown in Figure 30 and Table 1.

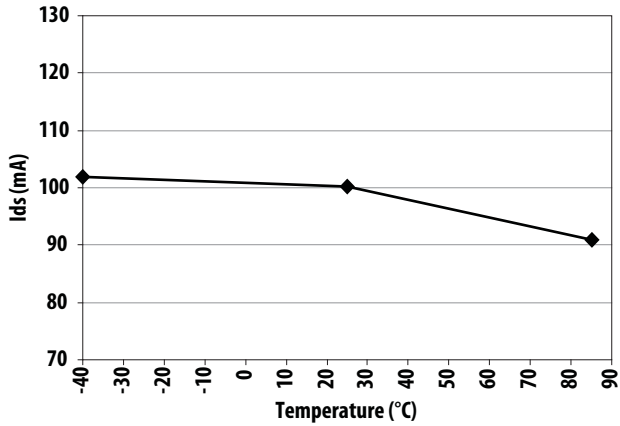


Figure 6. Ids over Temperature

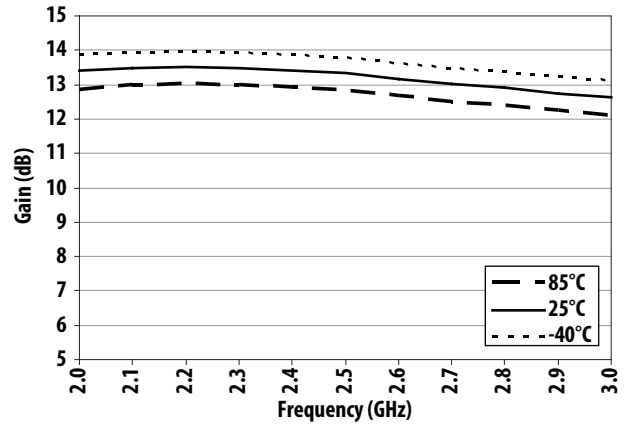


Figure 7. Gain over Frequency and Temperature

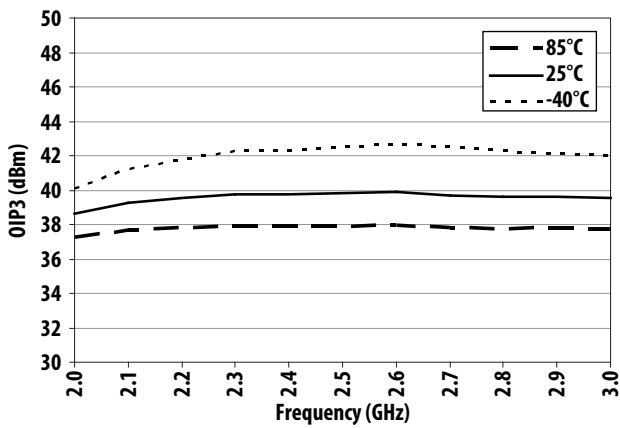


Figure 8. OIP3 over Frequency and Temperature

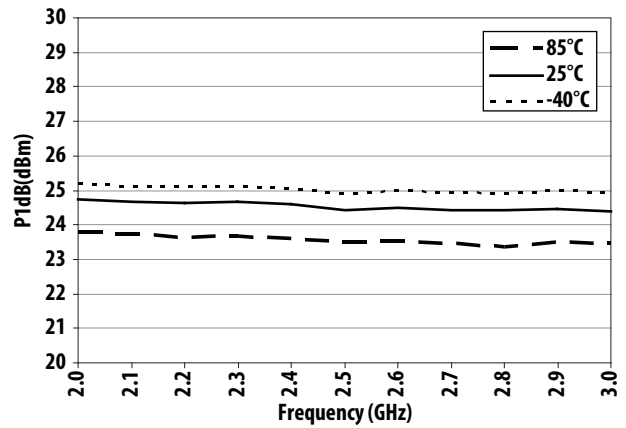


Figure 9. P1dB over Frequency and Temperature

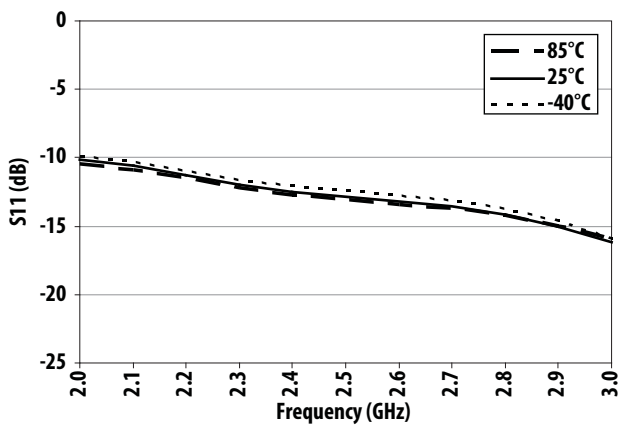


Figure 10. S11 over Frequency and Temperature

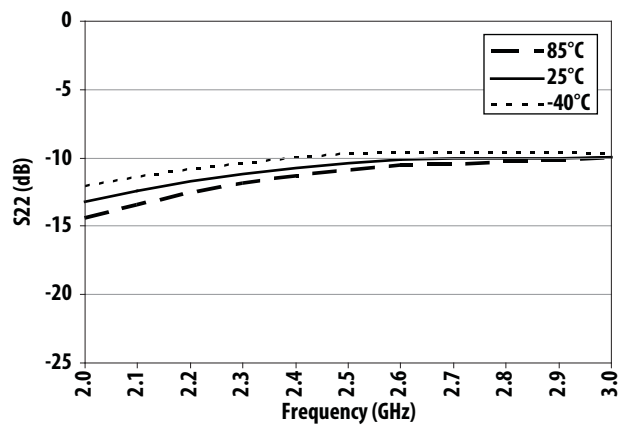


Figure 11. S22 over Frequency and Temperature

Typical Performance (2GHz - 3GHz)

T_A = 25°C, V_{dd} = 5V, Input Signal = CW unless stated otherwise. Application Test Circuit is shown in Figure 30 and Table 1.

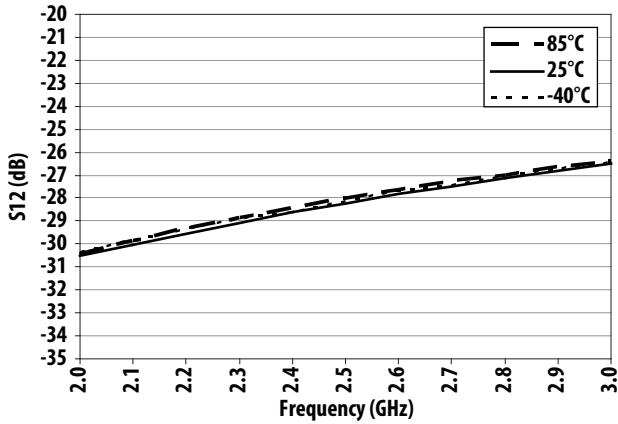


Figure 12. S12 over Frequency and Temperature

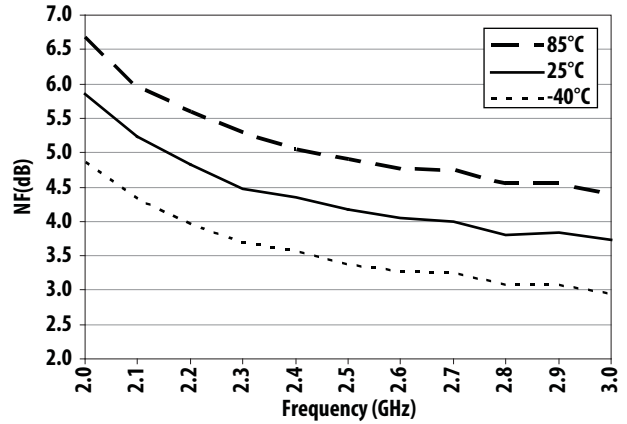


Figure 13. Noise Figure over Frequency and Temperature

Typical Performance (3GHz - 4GHz)

T_A = 25°C, V_{dd} = 5V, Input Signal=CW. Application Test Circuit is shown in Figure 30 and Table 2.

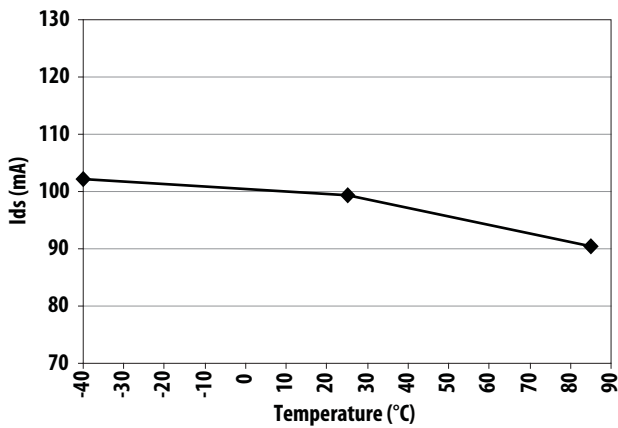


Figure 14. Ids over Temperature

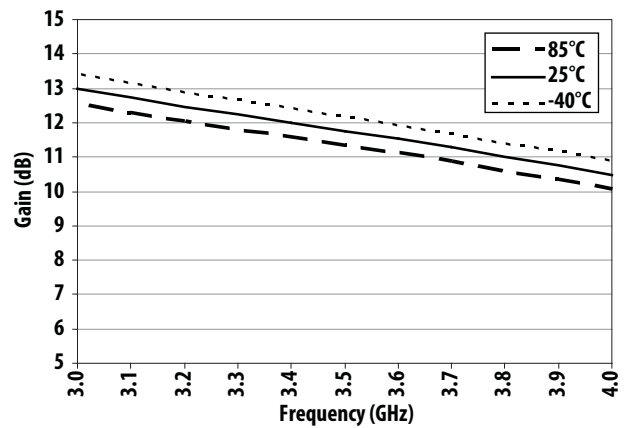


Figure 15. Gain over Frequency and Temperature

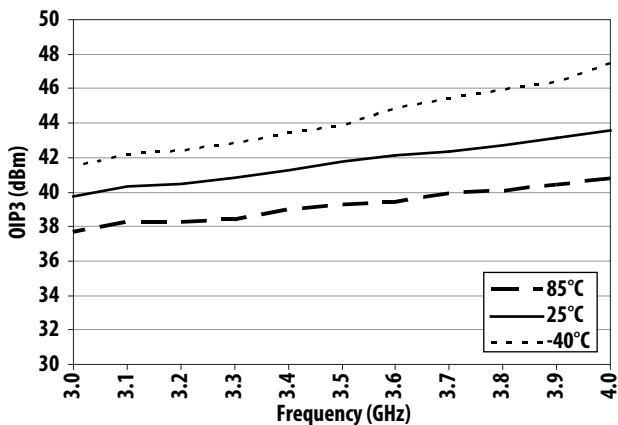


Figure 16. OIP3 over Frequency and Temperature

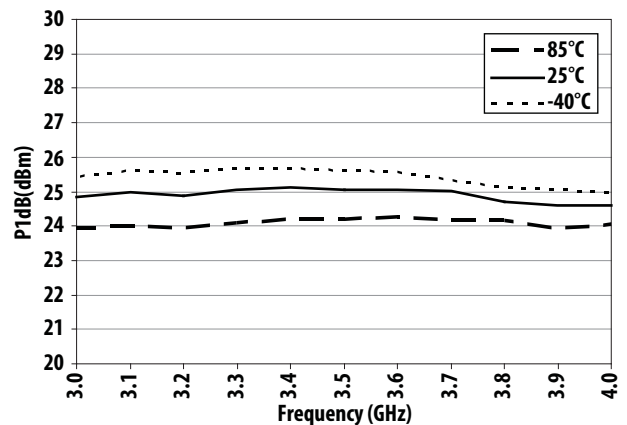


Figure 17. P1dB over Frequency and Temperature

Typical Performance (3GHz - 4GHz)

T_A = 25°C, V_{dd} = 5V, Input Signal=CW. Application Test Circuit is shown in Figure 30 and Table 2.

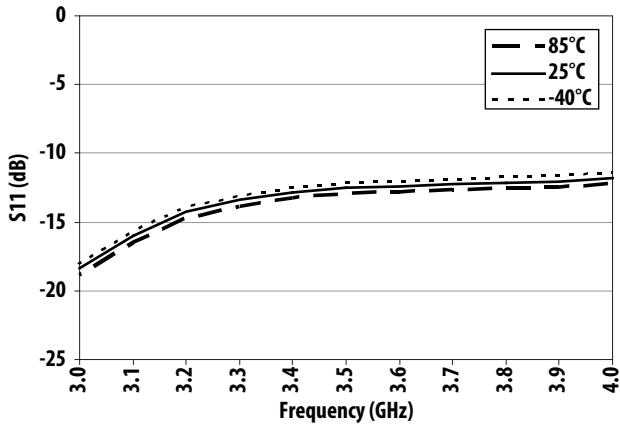


Figure 18. S11 over Frequency and Temperature

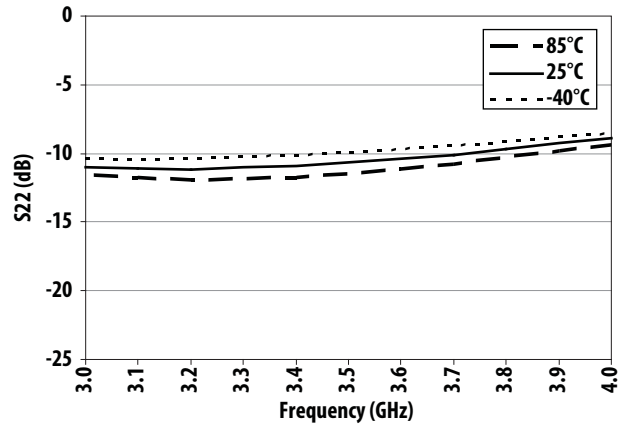


Figure 19. S22 over Frequency and Temperature

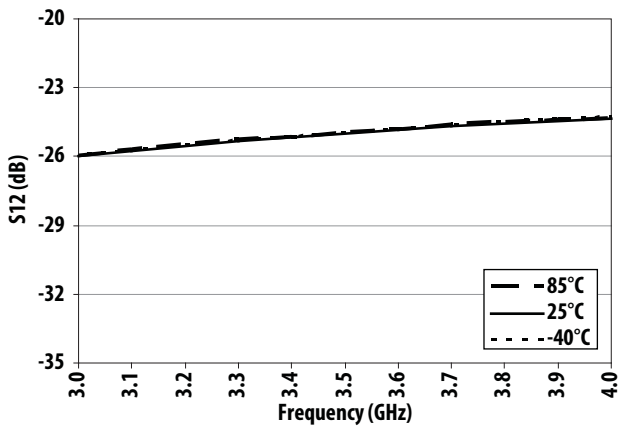


Figure 20. S12 over Frequency and Temperature

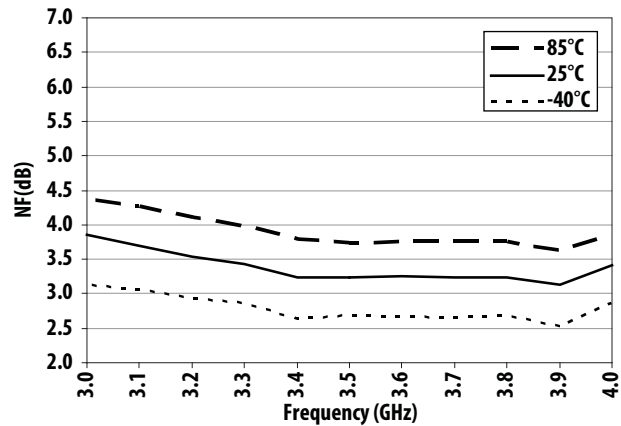


Figure 21. Noise Figure over Frequency and Temperature

Typical Performance (4GHz - 6GHz)

T_A = 25°C, V_{dd} = 5V, Input Signal=CW. Application Test Circuit is shown in Figure 30 and Table 3.

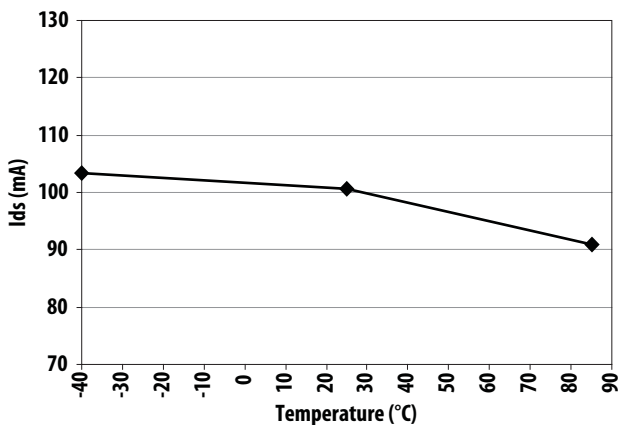


Figure 22. Ids over Temperature

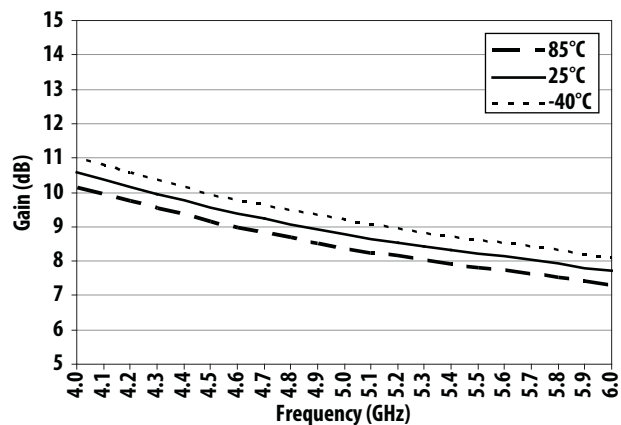


Figure 23. Gain over Frequency and Temperature

Typical Performance (4GHz - 6GHz)

T_A = 25°C, V_{dd} = 5V, Input Signal=CW. Application Test Circuit is shown in Figure 30 and Table 3.

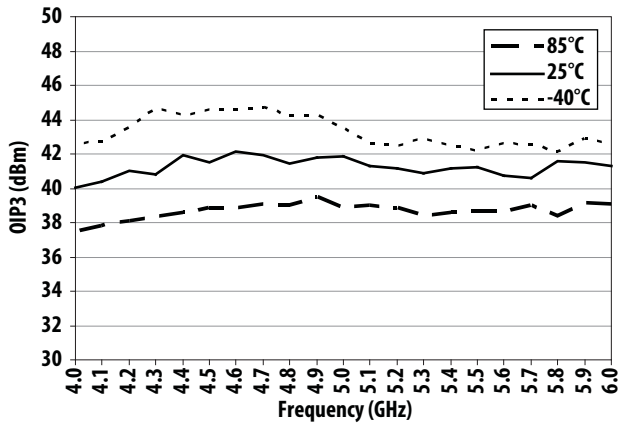


Figure 24. OIP3 over Frequency and Temperature

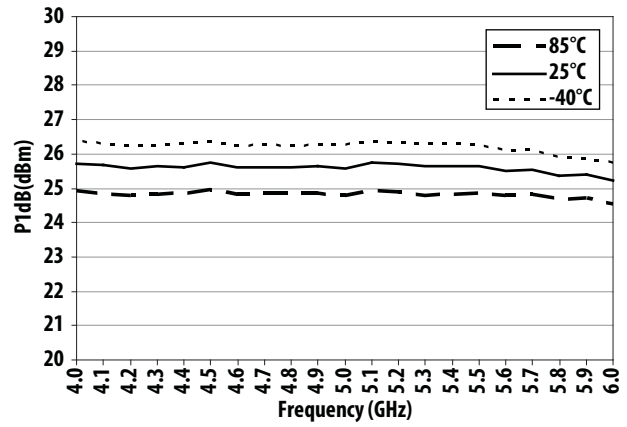


Figure 25. P1dB over Frequency and Temperature

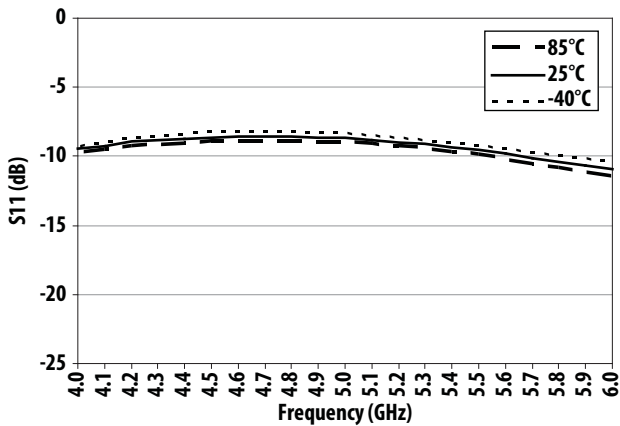


Figure 26. S11 over Frequency and Temperature

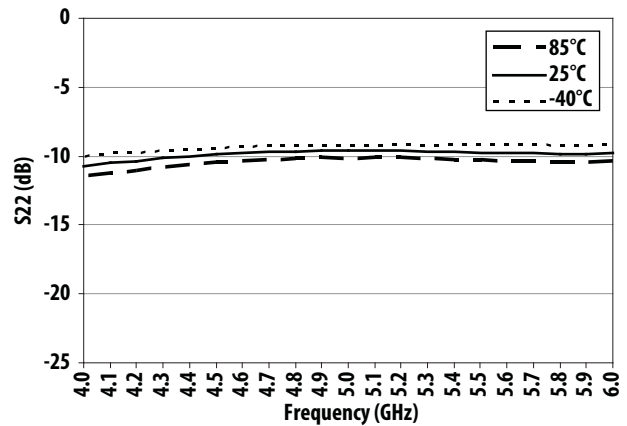


Figure 27. S22 over Frequency and Temperature

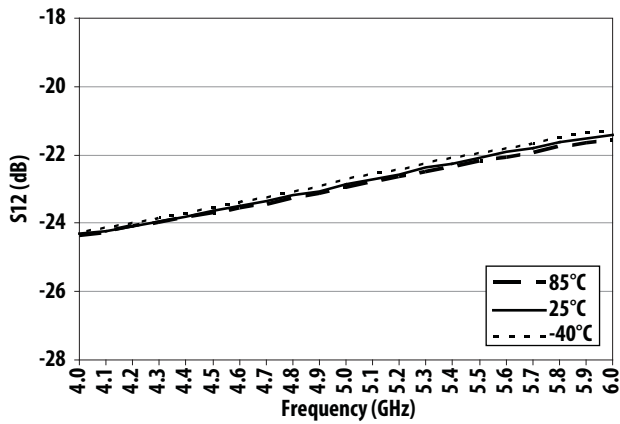


Figure 28. S12 over Frequency and Temperature

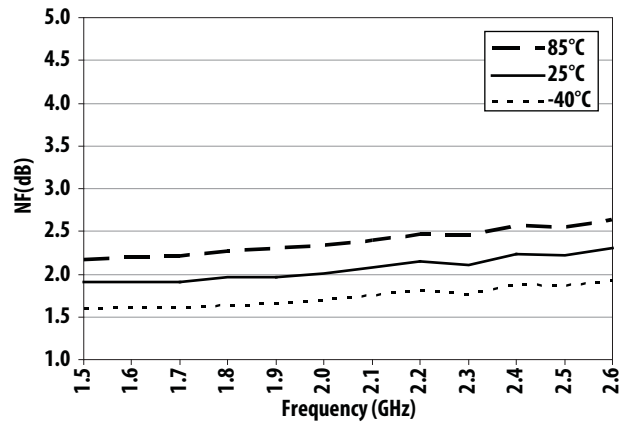


Figure 29. Noise Figure over Frequency and Temperature

Application Schematic Components Table and Demo Board

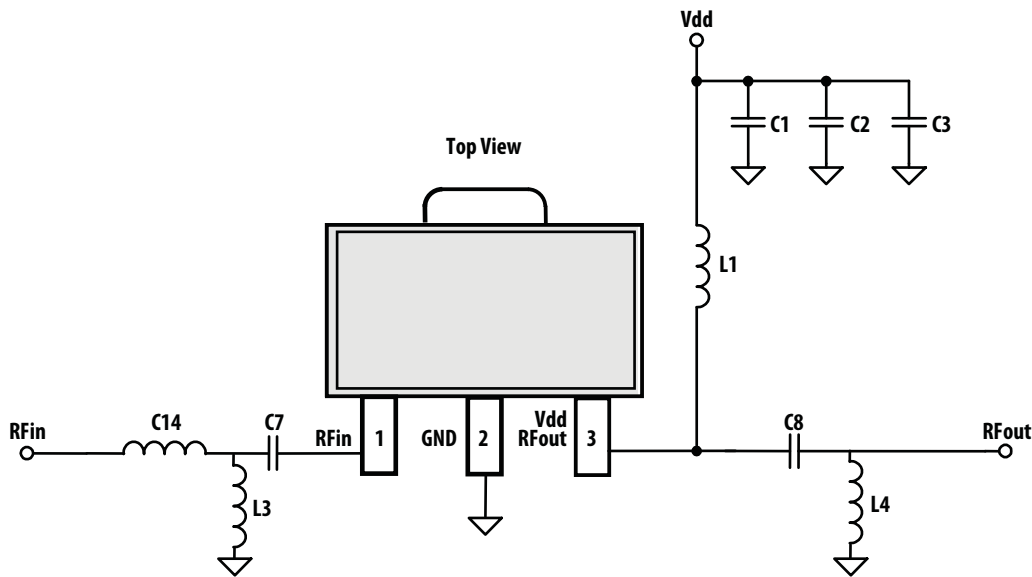


Figure 30. Application Schematic

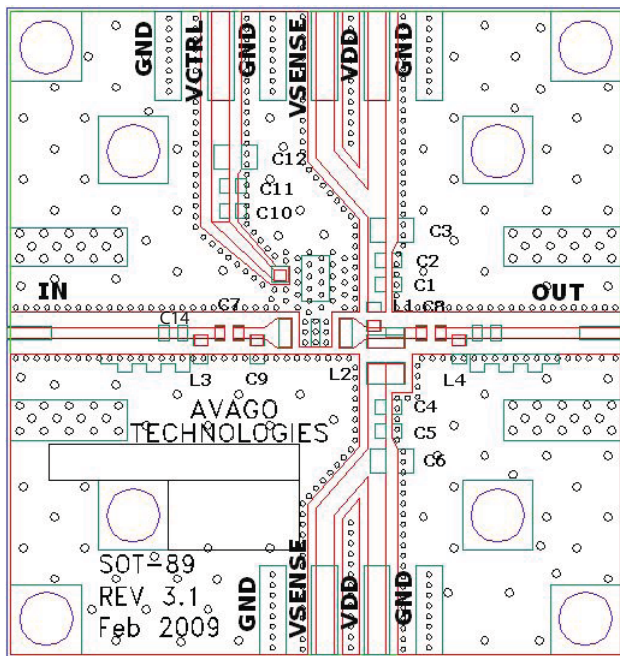


Figure 31. Demo board Layout

- Recommended PCB material is 10 mils Rogers RO4350, with FR4 backing for mechanical strength.
- Suggested component values may vary according to layout and PCB material.

Demo board Part List

Table 1. 2GHz - 3GHz Application Schematic Components

Circuit Symbol	Size	Value	Part Number	Description
L1	0402CS	19nH	0402CS-19NX (CoilCraft)	Wire Wound Chip Inductor
L3			NA	
L4	0402	4.3nH	0402CS-4N3X (CoilCraft)	Wire Wound Chip Inductor
C1	0402	100pF	GRM1555C1H101JZ01 (Murata)	Ceramic Chip Capacitor
C2	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C3	0805	2.2uF	GRM21BR61E225KA12L (Murata)	Ceramic Chip Capacitor
C7	0402	10pF	GRM1555C1H100JZ01 (Murata)	Ceramic Chip Capacitor
C8	0402	2.2pF	GRM1555C1H2R2CA01 (Murata)	Ceramic Chip Capacitor
C14	0402	1.2nH	LL1005-FHL1N2 (Toko)	MLC Inductor

Table 2. 3GHz - 4GHz Application Schematic Components

Circuit Symbol	Size	Value	Part Number	Description
L1	0603	4.7nH	0603CS-4N7X (CoilCraft)	Wire Wound Chip Inductor
L3			NA	
L4	0402	100nH	LL1005-FHLR10J (Toko)	MLC Inductor
C1	0402	100pF	GRM1555C1H101JZ01B (Murata)	Ceramic Chip Capacitor
C2	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C3	0805	2.2uF	GRM21BR61E225KA12L (Murata)	Ceramic Chip Capacitor
C7	0402	10pF	GRM1555C1H100JA01 (Murata)	Ceramic Chip Capacitor
C8	0402	5.6pF	GRM1555C1H5R6CA01 (Murata)	Ceramic Chip Capacitor
C14			NA	

Table 3. 4GHz - 6GHz Application Schematic Components

Circuit Symbol	Size	Value	Part Number	Description
L1	0603	5.1nH	LLQ1608-F5N1 (Toko)	Wire Wound Chip Inductor
L3	0402	4.7nH	LL1005-FHL4N7 (Toko)	MLC Inductor
L4			NA	
C1	0402	100pF	GRM1555C1H101JZ01 (Murata)	Ceramic Chip Capacitor
C2	0402	0.1uF	GRM155R71C104KA88D (Murata)	Ceramic Chip Capacitor
C3	0805	2.2uF	GRM21BR61E225KA12L (Murata)	Ceramic Chip Capacitor
C7	0402	2.2pF	CM05CH2R2C50AH (Kyocera)	Ceramic Chip Capacitor
C8	0402	2.2pF	CM05CH2R2C50AH (Kyocera)	Ceramic Chip Capacitor
C14			NA	

Test Circuit for S-Parameter and Noise Parameter

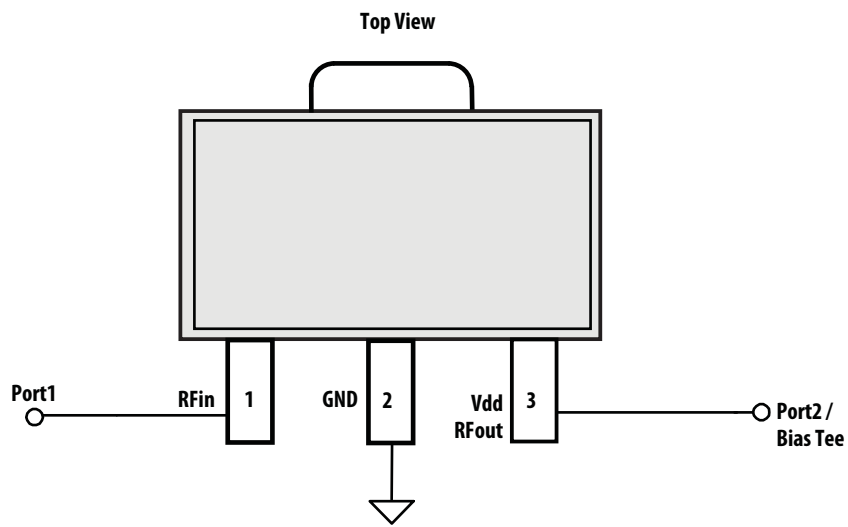


Figure 32. S-parameter and Noise parameter test circuit

Typical S-Parameter (Vdd = 5V, TA = 25°C, 50 ohm)

Freq (GHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
0.1	-0.89	171.29	-63.15	137.09	-70.77	74.72	-6.40	178.55
0.5	-0.87	134.26	-56.43	159.75	-58.33	62.10	-7.78	155.81
1	-1.28	79.26	-21.10	165.63	-53.76	50.95	-12.61	144.22
1.5	-2.61	5.44	3.05	90.24	-40.55	11.02	-13.88	-157.29
2	-8.89	-48.46	13.14	-45.05	-30.39	-122.16	-7.87	155.45
2.2	-10.88	-75.15	13.54	-82.79	-29.06	-158.46	-8.29	148.89
2.4	-14.73	-111.10	13.66	-114.23	-27.99	172.79	-7.98	144.64
2.6	-20.58	-165.76	13.51	-141.52	-27.15	148.77	-7.42	139.09
2.8	-22.68	110.04	13.18	-165.17	-26.55	129.02	-7.02	133.06
3	-20.20	53.49	12.79	174.17	-26.01	112.23	-6.75	127.76
3.2	-18.95	13.54	12.36	155.70	-25.56	97.67	-6.59	123.30
3.4	-18.13	-25.72	11.96	138.97	-25.14	84.61	-6.50	119.81
3.6	-16.60	-63.19	11.55	123.41	-24.75	72.79	-6.39	116.90
3.8	-14.55	-93.60	11.13	108.88	-24.41	61.86	-6.31	113.70
4	-12.62	-116.51	10.71	95.32	-24.10	51.65	-6.27	110.52
4.2	-11.03	-134.23	10.30	82.60	-23.82	41.96	-6.30	106.60
4.4	-9.89	-148.50	9.90	70.48	-23.57	33.02	-6.43	102.28
4.6	-9.17	-160.67	9.54	59.03	-23.29	24.51	-6.60	97.08
4.8	-8.72	-172.00	9.23	48.03	-22.99	16.15	-6.84	91.25
5	-8.54	176.59	8.95	37.24	-22.69	7.90	-7.06	84.67
5.2	-8.98	162.84	8.82	25.05	-22.25	-1.75	-7.37	70.40
5.4	-8.89	149.06	8.51	14.69	-22.01	-9.74	-7.27	65.40
5.6	-8.89	134.06	8.20	4.48	-21.79	-17.80	-7.09	60.58
5.8	-8.87	117.54	7.91	-5.83	-21.60	-26.09	-6.89	55.99
6	-8.74	99.65	7.58	-16.09	-21.45	-34.31	-6.67	51.77
6.2	-8.36	81.31	7.21	-26.36	-21.36	-42.67	-6.38	47.34
6.4	-7.71	63.61	6.82	-36.57	-21.32	-51.08	-6.06	42.69
6.6	-6.88	47.92	6.38	-46.67	-21.35	-59.31	-5.73	37.79
6.8	-6.01	34.84	5.86	-56.40	-21.46	-67.30	-5.43	32.62
7	-5.21	24.24	5.32	-65.48	-21.59	-74.72	-5.16	27.32
8	-3.02	-3.41	3.00	-103.98	-22.10	-105.83	-4.71	-5.35
9	-2.59	-27.30	1.34	-139.80	-22.25	-135.66	-4.53	-43.08
10	-2.12	-67.56	-0.79	-177.42	-23.00	-168.17	-3.86	-73.44
11	-1.21	-103.01	-4.16	150.87	-25.17	164.20	-2.79	-92.66
12	-0.80	-117.86	-7.00	130.49	-26.95	146.68	-2.33	-103.81
13	-0.88	-131.07	-8.26	108.78	-27.28	127.48	-2.27	-121.44
14	-1.02	-151.35	-8.82	81.73	-26.93	103.00	-2.42	-146.67
15	-0.93	-174.30	-10.38	52.63	-27.48	77.03	-2.03	-177.32
16	-0.83	173.31	-12.04	36.30	-27.78	64.17	-1.57	173.29
17	-0.93	162.53	-12.15	20.39	-26.28	48.69	-1.69	161.95
18	-1.09	149.25	-11.95	2.84	-24.66	32.64	-1.62	149.85
19	-1.52	132.50	-10.69	-19.47	-22.19	10.57	-2.31	131.12
20	-1.75	111.66	-10.17	-46.41	-20.49	-16.89	-2.46	104.29

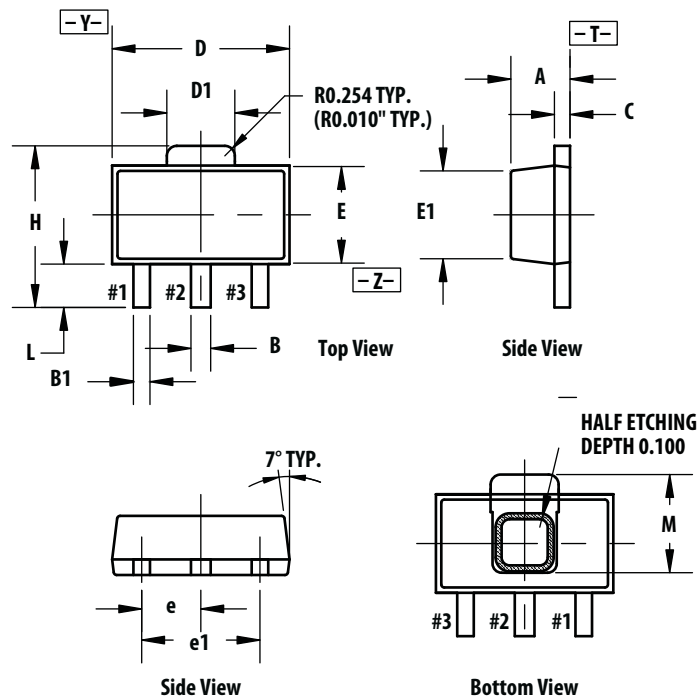
Typical Noise Parameters (V_{dd} = 5V, T_A = 25°C, 50 ohm)

Freq (GHz)	F _{min} (dB)	Γ _{opt} Mag	Γ _{opt} Ang	R _n /Z ₀
2.0	5.5	0.25	52	1.1
2.5	3.81	0.26	77	0.81
3.0	3.14	0.27	110	0.40
3.5	2.36	0.28	159	0.20
4.0	2.17	0.29	-163	0.19
4.5	2.28	0.30	-125	0.23
5.0	2.61	0.31	-97	0.38
5.5	2.68	0.32	-59	0.59
6.0	2.78	0.33	-27	0.53

Part Number Ordering Information

Part Number	No. of Devices	Container
MGA-30789-BLKG	100	Antistatic Bag
MGA-30789-TR1G	3000	13" Tape/Reel

SOT89 Package Dimensions

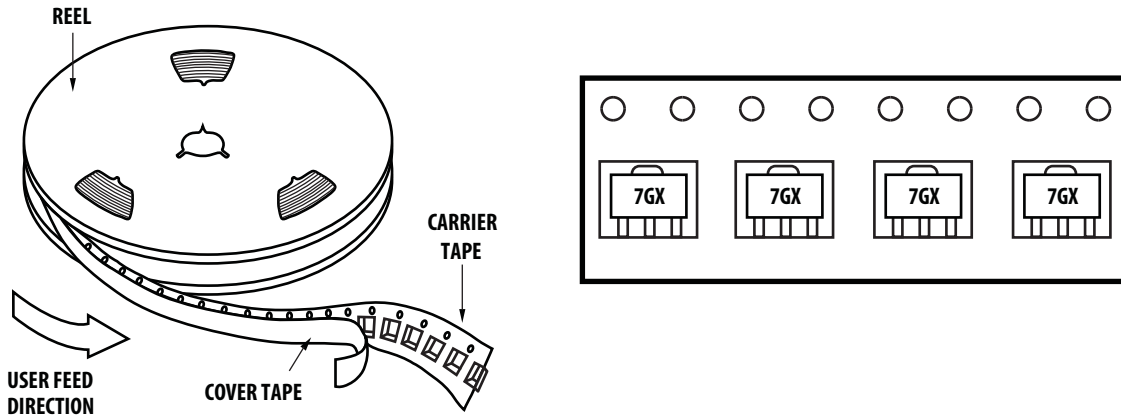


SYMBOL	COMMON					
	DIMENSIONS MILLIMETER			DIMENSIONS INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.40	1.50	1.60	0.055	0.059	0.063
B	0.44	0.50	0.56	0.017	0.0195	0.022
B1	0.36	0.42	0.48	0.014	0.0165	0.019
C	0.35	0.40	0.44	0.014	0.016	0.017
D	4.40	4.50	4.60	0.173	0.177	0.181
D1	1.62	1.73	1.83	0.064	0.068	0.072
E	2.30	2.50	2.60	0.090	0.096	0.102
E1	2.13	2.20	2.29	0.084	0.087	0.090
e	1.50 BSC			0.059 BSC		
e1	3.00 BSC			0.118 BSC		
H	3.95	4.10	4.25	0.155	0.161	0.167
L	0.90	1.10	1.20	0.035	0.038	0.047
M	2.36	2.46	2.56	0.093	0.097	0.101

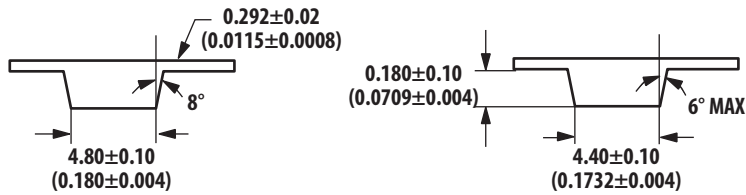
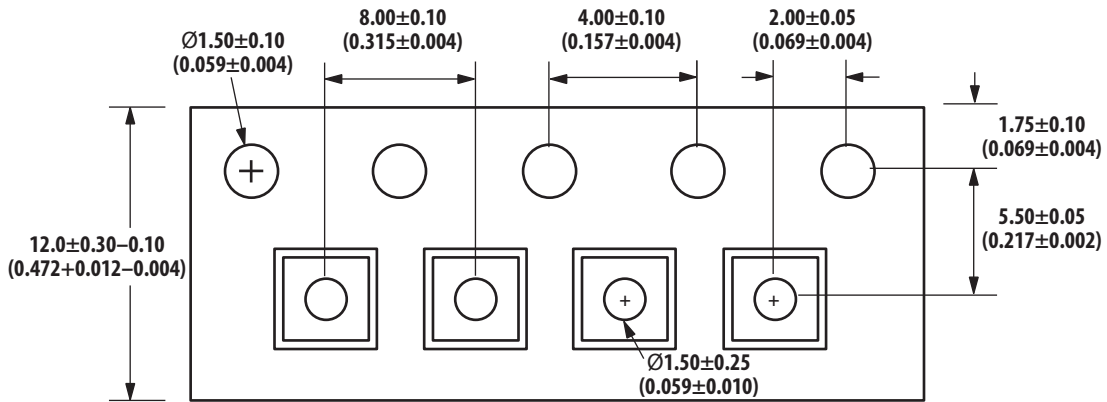
Note:

1. Dimensioning and tolerancing per ANSI.Y14.5M-1982
2. Controlling dimension: Millimeter conversions to inches are not necessarily exact
3. Dimension B1, 2 places.

Device Orientation

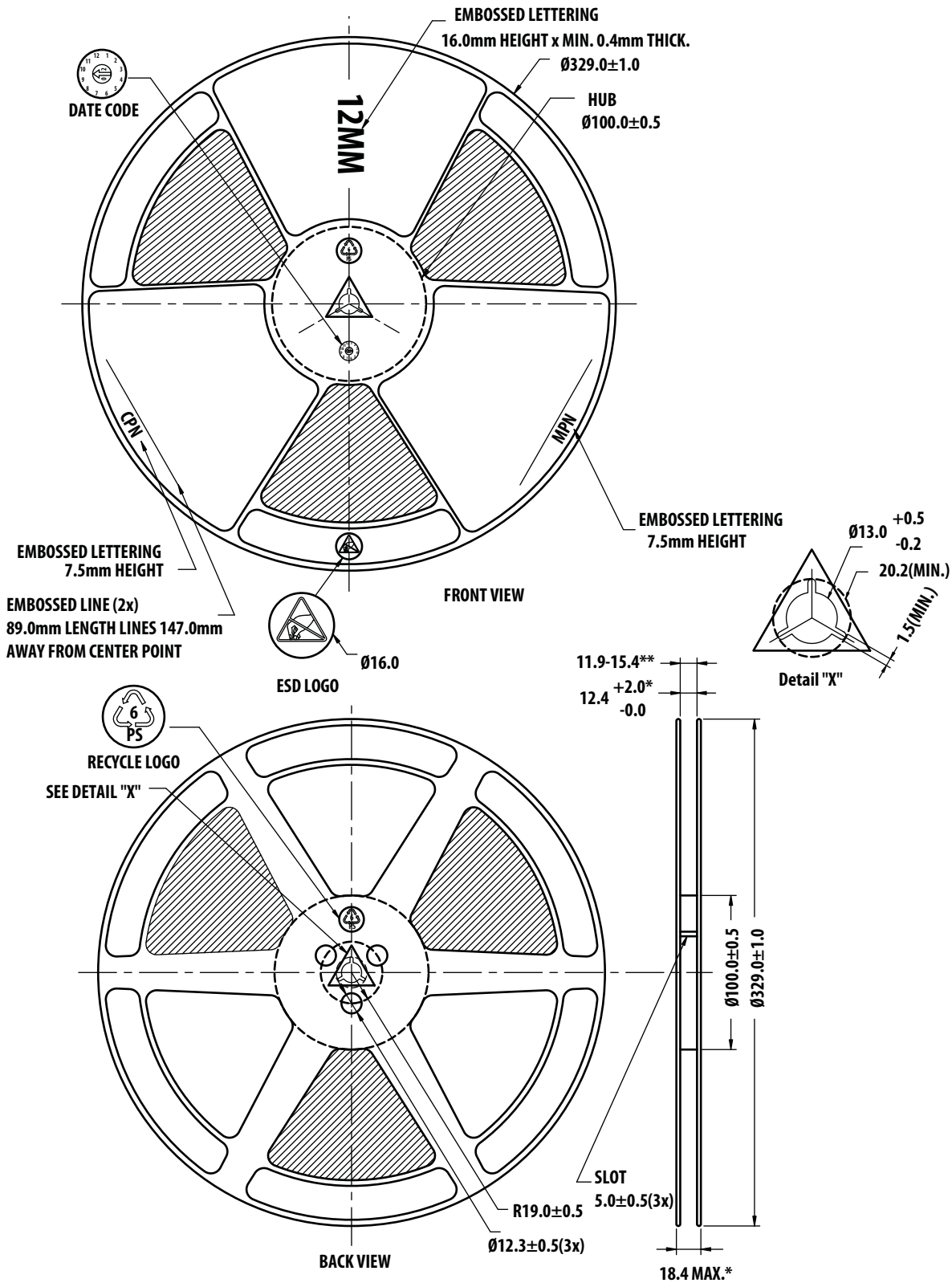


Tape Dimensions



Dimensions in mm (inches)

Reel Dimensions – 13" Reel 12mm width



For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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